# UNISONIC TECHNOLOGIES CO., LTD

UTG50N120-S

**Preliminary** 

Insulated Gate Bipolar Transistor

## 1200V TRENCH GATE FIELD-STOP IGBT

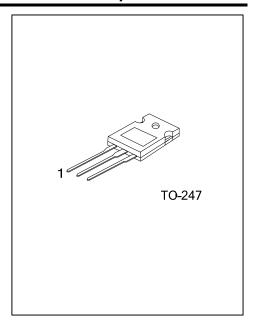
#### **■** DESCRIPTION

The UTC **UTG50N120-S** is an Trench Field-Stop Insulated Gate Bipolar Transistor. it uses UTC's advanced technology to provide customers with high switching speed, low saturation voltage and low switching loss, etc.

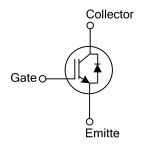
The UTC  ${\it UTG50N120-S}$  is suitable for the resonant or soft switching applications.

### **■ FEATURES**

- \* High switching speed
- \* High avalanche ruggedness
- \* Low saturation voltage:  $V_{CE(SAT).Typ.}$ =1.6V @ Ic=50A,  $V_{GE}$ =15V (T<sub>C</sub> =25°C)



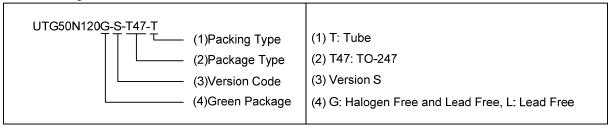
#### ■ SYMBOL



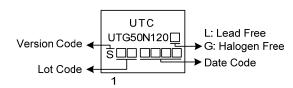
## ■ ORDERING INFORMATION

Ordering Number		Daalaaaa	Pin Assignment			Dl-i	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UTG50N120L-S-T47-T	UTG50N120G-S-T47-T	TO-247	G	С	E	Tube	

Note: Pin Assignment: G: Gate C: Collector E: Emitter



### MARKING



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## ■ ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Emitter Voltage		V <sub>CES</sub>	1200	V
Gate-Emitter Voltage		\/	±20	V
Transient Gate-emitter voltage (tp < 5 ms)		$V_{GES}$	±25	V
Cantinua Callantar Cumant	T <sub>C</sub> =25°C	Ic	100	Α
Continuous Collector Current	T <sub>C</sub> =100°C		50	Α
Collector Current Pulsed (Note 1)		I <sub>CM</sub>	200	Α
Diode Forward Current	T <sub>C</sub> =25°C	l <sub>F</sub>	100	Α
Diode Forward Current	T <sub>C</sub> =100°C		50	Α
Short Circuit Withstand Time $V_{\text{GE}} = 15\text{V}, \ V_{\text{CC}} \le 200\text{V}$ Allowed number of short circuits < 1000 Time between short circuits: $\ge 1.0\text{s}$ $T_{\text{VJ}} = 25^{\circ}\text{C}$		tsc		
				μs
			10	
Power Dissipation (T <sub>C</sub> =25°C)		$P_D$	285	W
Operating Junction Temperature		$T_J$	-40 ~ +150	°C
Storage Temperature Range		T <sub>STG</sub>	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

## **■ THERMAL DATA**

PARAMETER	SYMBOL	RATING	UNIT
Junction to Case	θјς	0.44	°C/W

<sup>2.</sup> Pulse width limited by maximum junction temperature.

## **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub>=25°C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT			
Off Characteristics			•		•				
Collector-Emitter Breakdown Voltage	BVces					V			
Collector Cut-Off Current	I <sub>CES</sub>	V <sub>CE</sub> =1200V, V <sub>GE</sub> =0V			5	μΑ			
G-E Leakage Current	I <sub>GES</sub>	V <sub>CE</sub> =0V, V <sub>GE</sub> =±20V			±100	nA			
On Characteristics									
Gate to Emitter Threshold Voltage	V <sub>GE(TH)</sub>	Ic=250µA, Vce=Vge	4.5		6.5	V			
Collector to Emitter Saturation Voltage	V/	I <sub>C</sub> =50A, V <sub>GE</sub> =15V		1.6	2.1	V			
Collector to Efficier Saturation voltage	V <sub>CE(SAT)</sub>	T <sub>C</sub> =125°C		2.0		V			
Dynamic Characteristics									
Input Capacitance	CIES			2940		pF			
Output Capacitance	Coes	V <sub>CE</sub> =25V, V <sub>GE</sub> =0V, f=1MHz		227		рF			
Reverse Transfer Capacitance	CRES			41		pF			
Switching Characteristics									
Total Gate Charge	Q <sub>G</sub>			143		nC			
Gate-Emitter Charge	QGE	Vce=600V, Ic=50A, VGE=15V		31.4		nC			
Gate-Collector Charge	Q <sub>GC</sub>			70.6		nC			
Turn-On Delay Time	t <sub>DON)</sub>			26.6		ns			
Rise Time	t <sub>R</sub>			47.2		ns			
Turn-Off Delay Time	t <sub>DOFF)</sub>	$V_{CC}$ =600 $V$ , $I_{C}$ =50 $A$ , $R_{G}$ =5 $\Omega$ ,		162.1		ns			
Fall Time	t⊧	V <sub>GE</sub> =0~15V, L=500uH		160.2		ns			
Turn-On Switching Loss	Eon			3.778		mJ			
Turn-Off Switching Loss	Eoff			3.596		mJ			
SOURCE- DRAIN DIODE RATINGS AND	CHARACTE	RISTICS							
Forward Voltage Drop	VF	I <sub>F</sub> =20A			3.0	V			
Reverse Recovery Time	t <sub>rr</sub>	1 - FOA - 41/4+-400A/v-C \/ COO		84.6		ns			
Reverse Recovery Charge	Qrr	I <sub>F</sub> =50A, dI/dt=100A/μS, V <sub>CC</sub> =600V		3.2		μC			

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